

S-SWIFT™ Technology

Substrate-SWIFT (S-SWIFT) technology, also known as Silicon Wafer Integrated Fan-Out (on Substrate), is revolutionizing the world of advanced packaging. By boosting I/O and circuit density while shrinking the footprint and profile, S-SWIFT is the go-to solution for both single-die and multi-die applications, perfectly aligning with the escalating demand for higher IC integration in mobile and networking devices.

S-SWIFT stands out as a game-changer in heterogeneous IC packaging, enabling high-performance, cost-effective integration of multiple chiplets and memories. This technology not only increases I/O and circuit density but also paves the way for advanced 3D structures, making it indispensable for the next generation of mobile and networking applications.

Fan-Out Meets Substrate

An innovative alternative to 2.5D TSV, S-SWIFT is a fan-out package that enhances chip performance and reduces costs. By flip-chip mounting chips onto a high pin count ball grid array (BGA) substrate, and incorporating a re-distribution layer (RDL) for shorter die-to-die (D2D) interconnections, S-SWIFT treats the entire fan-out package as a single die. This intelligent design is then mounted onto the BGA substrate, offering a cost-effective alternative to traditional 2.5D Through Silicon Via (TSV) technology. A key feature of S-SWIFT is its re-distribution layer (RDL), which enables shorter die-to-die (D2D) interconnections between multiple chips. This design effectively treats the entire fan-out package as a single die, which is then mounted onto the BGA substrate.

By integrating these advanced features, S-SWIFT offers a cost-effective alternative to traditional 2.5D Through Silicon Via (TSV) technology.

Key Features

Package Structure

- ▶ Fan-out package flip-chip mounted on a high pin count BGA substrate
- ▶ RDL facilitates shorter D2D interconnections between multiple chips

Chip Integration

- ▶ Integrates multiple chiplets within a single package
- ▶ Chiplets can be different functional units, such as ASICs or HBMs

Interposer-less Design

- ▶ Eliminates the need for an interposer, reducing complexity and costs

Electrical Performance

- ▶ Offers excellent electrical performance due to shorter D2D connections
- ▶ Features less insertion loss, better impedance control, and lower warpage

High I/O Density

- ▶ Supports high I/O counts (>1000)
- ▶ Ideal for large package sizes and networking/server applications

S-SWIFT™ PACKAGING CONSIDERATIONS

S-SWIFT is a revolutionary technology transforming the semiconductor industry. This advanced packaging technology enables high-density fan-out (HDFO), providing superior performance, reliability and cost-effectiveness.

FEATURES

- ▶ Polymer dielectrics
- ▶ Multi-die and large die capability
- ▶ Large body package capability
- ▶ High-density interconnects
- ▶ Miniaturization
- ▶ Cost efficiency
- ▶ Thermal management
- ▶ Integration flexibility

APPLICATIONS

- ▶ High Performance Computing (HPC)
- ▶ Heterogeneous integration
- ▶ Functional chip integration (CPU/GPU)
- ▶ System-on-Chip (SoC) partitioning
- ▶ Multi-die configurations
- ▶ 3D PoP-compatible applications
- ▶ High-performance mobile application processors and baseband devices

S-SWIFT™ Technology

Benefits

- ▶ **Cost-effective:** Eliminates the need for an interposer, reducing package costs
- ▶ **Electrical Performance:** Offers better impedance control, lower insertion loss, and less warpage, resulting in improved electrical performance
- ▶ **High I/O Counts:** Supports packages with over 1000 I/Os, making it ideal for networking and server applications
- ▶ **Time to Market:** Leveraging existing fan-out/flip chip techniques, this technology accelerates time to market

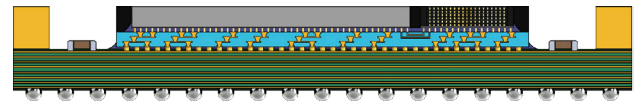
Applications

S-SWIFT™ technology is well-suited for applications that require large package sizes and high I/O density (>1000).

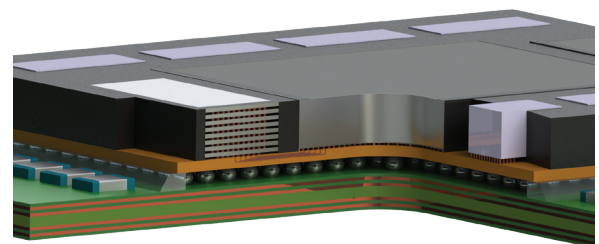
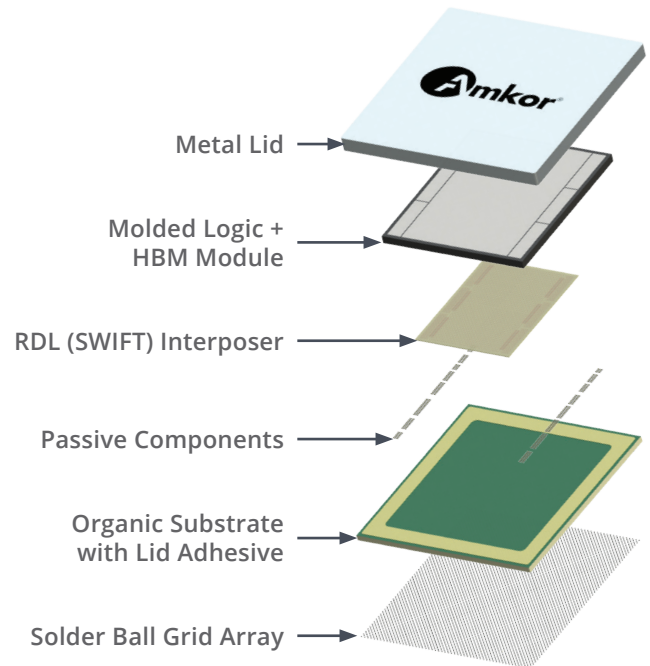
Key applications include

- ▶ **High Performance Computing (HPC):** Enhances HPC applications by efficiently achieving critical interconnections
- ▶ **Networking and Server Applications:** High I/O density makes S-SWIFT ideal for networking and server needs
- ▶ **Artificial Intelligence (AI):** Exceptional electrical performance and high-speed, low-latency chip-to-chip interconnect are perfect for AI applications requiring significant memory and compute power
- ▶ **ASICs and HBMs:** The chip-last technology of S-SWIFT is suitable for packaging ASICs and HBMs

S-SWIFT™ technology offers lower costs compared to 2.5D, a thinner package, reduced insertion loss, improved impedance control, and lower warpage, resulting in superior electrical performance. These advantages make S-SWIFT a compelling choice for relevant applications.



Substrate SWIFT® Technology



S-SWIFT™ Cross Section



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